

High Performance Schottky Rectifier, 1.0 A


SMB


FEATURES

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

PRODUCT SUMMARY	
Package	SMB
$I_{F(AV)}$	1.0 A
V_R	30 V
V_F at I_F	0.420 V
I_{RM} max.	15 mA at 125 °C
T_J max.	150 °C
Diode variation	Single die
E_{AS}	3.0 mJ

DESCRIPTION

The VS-10BQ030PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	1.0	A
V_{RRM}		30	V
I_{FSM}	$t_p = 5$ ms sine	430	A
V_F	1.0 A _{pk} , $T_J = 125$ °C	0.30	V
T_J	Range	-55 to +150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10BQ030PbF	UNITS
Maximum DC reverse voltage	V_R	30	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 106 °C, rectangular waveform		1.0	A
Maximum peak one cycle non-repetitive surge current See fig. 6	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	430	A
		10 ms sine or 6 ms rect. pulse		90	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 6 mH		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop	$V_{FM}^{(1)}$	1 A	$T_J = 25\text{ }^{\circ}\text{C}$	0.420	V	
		2 A		0.470		
		1 A	$T_J = 125\text{ }^{\circ}\text{C}$	0.300		
		2 A		0.370		
Maximum reverse leakage current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = \text{Rated } V_R$	0.5	mA	
		$T_J = 100\text{ }^{\circ}\text{C}$		5.0		
		$T_J = 125\text{ }^{\circ}\text{C}$		15		
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^{\circ}\text{C}$		200	pF	
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		2.0	nH	
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s	

Note(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$		-55 to +150	$^{\circ}\text{C}$
Maximum thermal resistance, junction to lead	$R_{thJL}^{(2)}$	DC operation	25	$^{\circ}\text{C/W}$
Maximum thermal resistance, junction to ambient	R_{thJA}		80	
Approximate weight			0.10	g
			0.003	oz.
Marking device		Case style SMB (similar DO-214AA)	V1E	

Notes(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

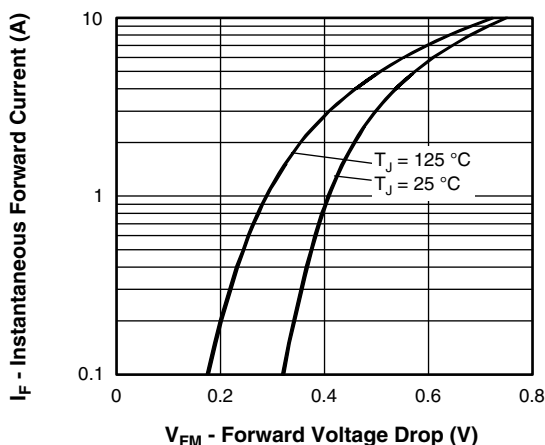


Fig. 1 - Maximum Forward Voltage Drop Characteristics

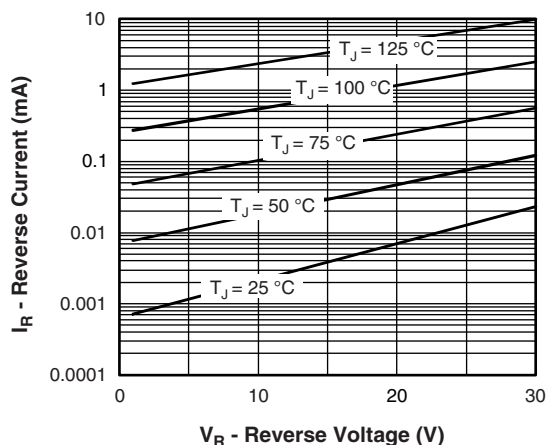


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

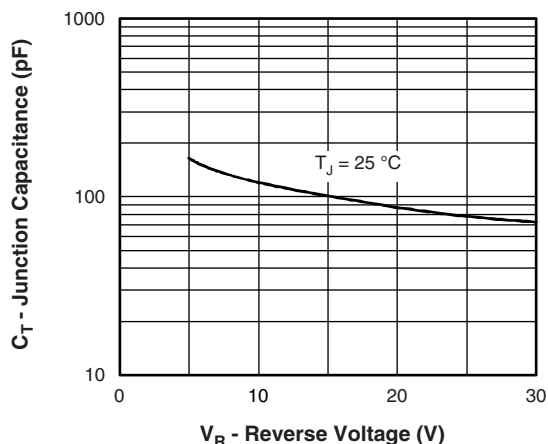


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

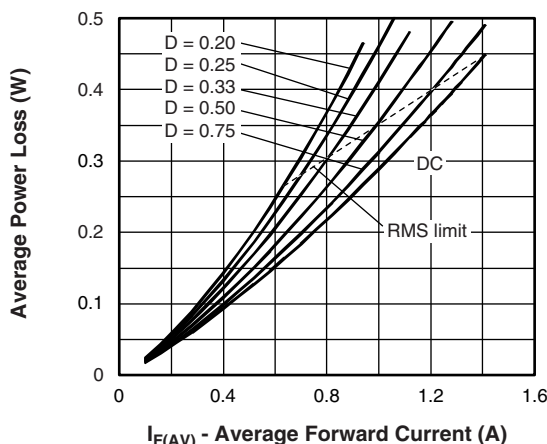


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

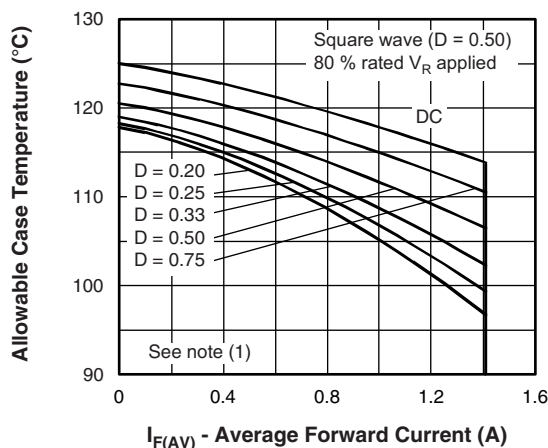


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

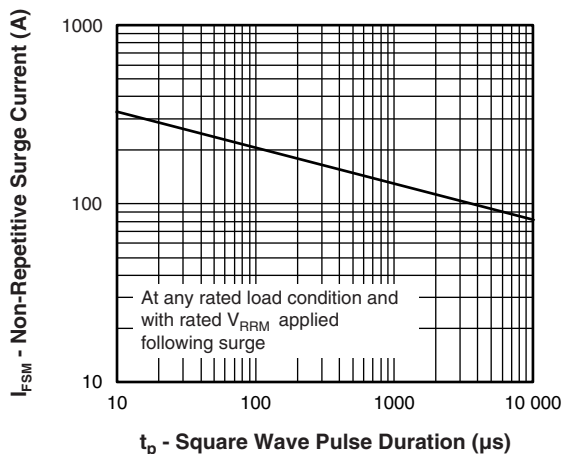


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



ORDERING INFORMATION TABLE

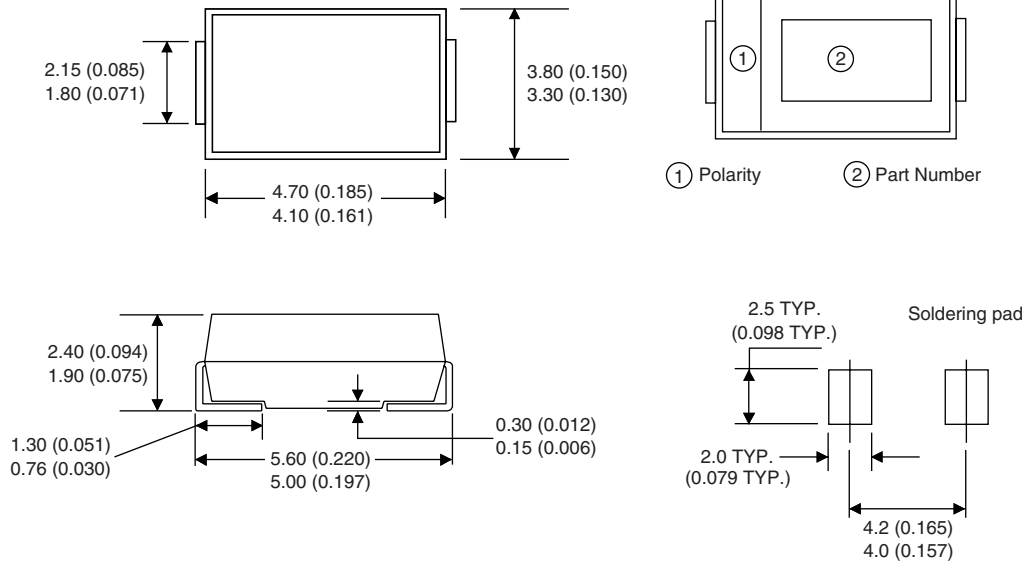
Device code	VS-	10	B	Q	030	TR	PbF
	1	2	3	4	5	6	7
1	- Vishay Semiconductors product						
2	- Current rating						
3	- B = single lead diode						
4	- Q = Schottky "Q" series						
5	- Voltage rating (030 = 30 V)						
6	- • None = box (1000 pieces) • TR = tape and reel (3000 pieces)						
7	- PbF = lead (Pb)-free						

LINKS TO RELATED DOCUMENTS		
Dimensions		
Part marking information		www.vishay.com/doc?95029
Packaging information	Tape and reel	www.vishay.com/doc?95034
	Bulk	www.vishay.com/doc?95397



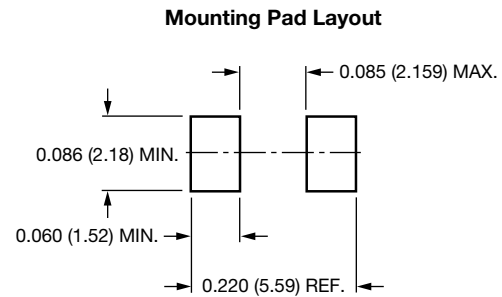
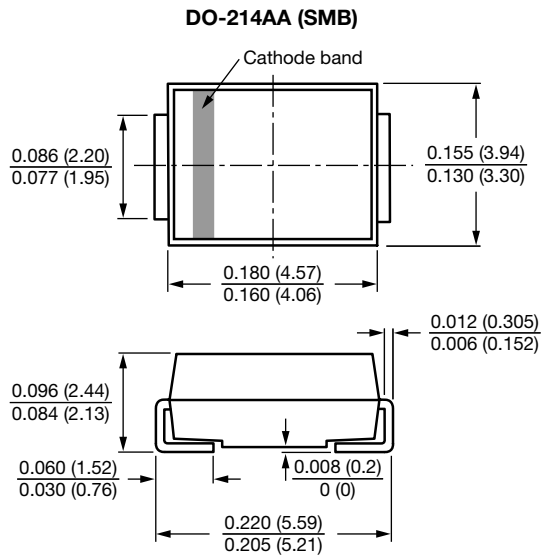
SMB

DIMENSIONS in millimeters (inches)



SMB

DIMENSIONS in inches (millimeters)





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